NSN 5961-00-888-4980

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.170 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.076 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 breakover voltage, dc and 500.0 forward voltage, peak
Current Rating Per Characteristic:
10.00 milliamperes source cutoff current preset
Special Features:
Junction pattern arrangement: npnp
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0